



SLLS667B-FEBRUARY 2006-REVISED JUNE 2008

# 3.3 V FULL-DUPLEX RS-485/RS-422 DRIVERS AND BALANCED RECEIVERS

#### **FEATURES**

Designed for INTERBUS Applications

**UMENTS** 

- Designed for RS-422 and RS-485 Networks
- Balanced Receiver Thresholds
- 1/2 Unit-Load (up to 64 nodes on the bus)
- Bus-Pin ESD Protection 15 kV HBM
- Bus-Fault Protection of –7 V to 12 V
- Thermal Shutdown Protection
- Power-Up/Down Glitch-free Bus Inputs and Outputs
- High Input Impedance With Low V<sub>CC</sub>
- Monotonic Outputs During Power Cycling
- 5-V Tolerant Inputs

### **APPLICATIONS**

- Digital Motor Control
- Utility Meters
- Chassis-to-Chassis Interconnections
- Electronic Security Stations
- Industrial, Process, and Building Automation
- Point-of-Sale (POS) Terminals and Networks
- DTE/DCE Interfaces

### **DESCRIPTION**

The SN65HVD379 is a differential line driver and differential-input line receiver that operates with a 3.3-V power supply. Each driver and receiver has separate input and output pins for full-duplex bus communication designs. They are designed for balanced transmission lines and interoperation with ANSI TIA/EIA-485A, TIA/EIA-422-B, ITU-T v.11, and ISO 8482:1993 standard-compliant devices.

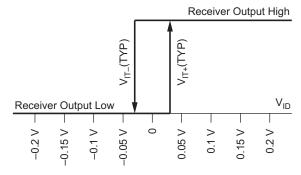
These differential bus drivers and receivers are monolithic, integrated circuits designed for full-duplex bi-directional data communication on multipoint bus-transmission lines at signaling rates<sup>(1)</sup> up to 25 Mbps. The SN65HVD379 is fully enabled with no external enabling pins.

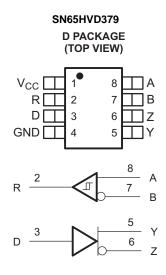
The 1/2 unit load receiver has a higher receiver input resistance. This results in lower bus leakage currents over the common-mode voltage range, and reduces the total amount of current that an RS-485 driver is forced to source or sink when transmitting.

The balanced differential receiver input threshold makes the SN65HVD379 more compatible with fieldbus requirements that define an external failsafe structure.

 The signaling rate of a line is the number of voltage transitions that are made per second expressed in the units bps (bits per second).

#### **BALANCED RECEIVER INPUT THRESHOLDS**







Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### **ORDERING INFORMATION**

SIGNALING RATE	UNIT LOADS	PART NUMBER (1)	SOIC MARKING
25 Mbps	1/2	SN65HVD379	

(1) These are The D package is available taped and reeled. Add an R suffix to the part number (ie. SN65HVD379DR).

#### **ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range unless otherwise noted(1) (2)

		UNIT
$V_{CC}$	Supply voltage range	-0.3 V to 6 V
$V_A, V_B, V_Y, V_Z$	Voltage range at any bus terminal (A, B, Y, Z)	–9 V to 14 V
V <sub>TRANS</sub>	Voltage input, transient pulse through 100 Ω. See Figure 8 (A, B, Y, Z) <sup>(3)</sup>	–50 to 50 V
V <sub>I</sub>	Input voltage range (D, DE, RE)	-0.5 V to 7 V
P <sub>CONT</sub>	Continuous total power dissipation	Internally limited <sup>(4)</sup>
Io	Output current (receiver output only, R)	11 mA

<sup>(1)</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range unless otherwise noted

PARAME	ARAMETER				MAX	UNIT
V <sub>CC</sub>	Supply voltage	Supply voltage				V
$V_{\text{I}}$ or $V_{\text{IC}}$	Voltage at any bus termina	I (separately or common mode)	-7 <sup>(1)</sup>		12	V
1/t <sub>UI</sub>	Signaling rate	SN65HVD379			25	Mbps
$R_L$	Differential load resistance		54	60		Ω
$V_{\text{IH}}$	High-level input voltage	2		$V_{CC}$		
$V_{IL}$	Low-level input voltage	0		8.0	V	
$V_{\text{ID}}$	Differential input voltage	Differential input voltage				
1	High lovel output ourrent	Driver	-60			mA
ІОН	High-level output current	Receiver	-8			ША
1	Low lovel output ourrent	Driver			60	mA
lOL	Low-level output current	Receiver			8	ША
T <sub>A</sub>	Ambient still-air temperatur	e	-40		85	С

(1) The algebraic convention, in which the least positive (most negative) limit is designated as minimum is used in this data sheet.

<sup>(2)</sup> All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

<sup>(3)</sup> This tests survivability only and the output state of the receiver is not specified.

<sup>(4)</sup> The Thermal shutdown protection circuit internally limits the continuous total power dissipation. Thermal shutdown typically occurs when the junction temperature reaches 165C.

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#### **ELECTROSTATIC DISCHARGE PROTECTION**

PARAMETER	TEST CONDITIONS	MIN TYP <sup>(1)</sup> MAX	UNIT
Human body model	Bus terminals and GND	16	
Human body model <sup>(2)</sup>	All pins	4	kV
Charged-device-model <sup>(3)</sup>	All pins	1	

- (1) All typical values at 25C with 3.3-V supply.
- (2) Tested in accordance with JEDEC Standard 22, Test Method A114-A.
- (3) Tested in accordance with JEDEC Standard 22, Test Method C101.

#### DRIVER ELECTRICAL CHARACTERISTICS

over recommended operating conditions unless otherwise noted

	PARAMET	ER	TEST COND	ITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
V <sub>I(K)</sub>	Input clamp voltage		I <sub>I</sub> = -18 mA	$I_I = -18 \text{ mA}$				
			I <sub>O</sub> = 0	I <sub>O</sub> = 0			V <sub>CC</sub>	
157	Ota a di catata diffananti	int number of tracks	$R_L = 54 \Omega$ , See Figure	1 <sup>(2)</sup> (RS-485)	1.5	2.0		
$ V_{OD(SS)} $	Steady-state different	iai output voitage	$R_L = 100 \Omega$ , See Figure	e 1 (RS-422)	2	2.3		
			$V_{\text{test}} = -7 \text{ V to } 12 \text{ V, Se}$	ee Figure 2	1.5			
$\Delta  V_{OD(SS)} $	Change in magnitude differential output volt		$R_L = 54 \Omega$ , See Figure	1 and Figure 2	-0.2		0.2	V
V <sub>OD(RING)</sub>	Differential output volt undershoot	age overshoot and	$R_L = 54 \Omega$ , $C_L = 50 pF$ . (Figure 3 for definitions				10% <sup>(3)</sup>	
V <sub>OC(PP)</sub>	Peak-to-peak commo	n-mode output voltage				0.5		
V <sub>OC(SS)</sub>	Steady-state common	-mode output voltage	See Figure 3		1.6		2.3	
$\Delta V_{OC(SS)}$	Change in steady-stativoltage	te common-mode output	- Coo rigaro c		-0.05		0.05	
11	High installance state		$V_{CC} = 0 \text{ V}, V_{Z} \text{ or } V_{Y} = 0$ Other input at 0 V	$V_{CC} = 0 \text{ V}, V_{Z} \text{ or } V_{Y} = 12 \text{ V},$ Other input at 0 V			90	^
$I_{Z(Z)}$ or $I_{Y(Z)}$	High-impedance state	output current	$V_{CC} = 0 \text{ V}, V_Z \text{ or } V_Y = 0$ Other input at 0 V	–7 V,	-10			μΑ
I <sub>Z(S)</sub> or	Short-circuit output current <sup>(4)</sup>		$V_Z$ or $V_Y = -7 \text{ V}$	Other input	-250		250	A
I <sub>Y(S)</sub>			$V_Z$ or $V_Y = 12 V$	at 0 V	-250		250	mA
I	Input current D		$V_{I} = 0 \text{ or } V_{I} = 2.0$		0		100	Α
C <sub>(OD)</sub>	Differential output cap	pacitance	$V_{OD} = 0.4 \sin (4E6\pi t) + V_{CC} \text{ at } 0 \text{ V}$	+ 0.5 V,		16		pF

- (1) All typical values are at 25C and with a 3.3-V supply.
- (2) V<sub>CC</sub> is 3.3 Vdc 5%
- (3) 10% of the peak-to-peak differential-output voltage swing, per TIA/EIA-485.
- (4) Under some conditions of short-circuit to negative voltages, output currents exceeding the ANSI TIA/EIA-485-A maximum current of 250 mA may occur. Continuous exposure may affect device reliability.

### DRIVER SWITCHING CHARACTERISTICS

over recommended operating conditions unless otherwise noted

	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
t <sub>PLH</sub>	Propagation delay time, low-to-high-level output		4	10	10	no
t <sub>PHL</sub>	Propagation delay time, high-to-low-level output		4	10	18	ns
t <sub>r</sub>	Differential output signal rise time	$R_L = 54 \Omega$ , $C_L = 50 pF$ , See Figure 5	2.5	-	12	20
t <sub>f</sub>	Differential output signal fall time		2.5	5	12	ns
t <sub>sk(p)</sub>	Pulse skew ( t <sub>PHL</sub> - t <sub>PLH</sub>  )			0.6		ns
t <sub>sk(pp)</sub> (2)	Part-to-part skew			1		ns

(1) All typical values are at 25C and with a 3.3-V supply.

(2) t<sub>sk(pp)</sub> is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

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### RECEIVER ELECTRICAL CHARACTERISTICS

over recommended operating conditions unless otherwise noted

	PARAMETER	TEST CONDITIO	NS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
$V_{IT+}$	Positive-going differential input threshold voltage	$I_O = -8 \text{ mA}$				0.2	
V <sub>IT-</sub>	Negative-going differential input threshold voltage	I <sub>O</sub> = 8 mA	I <sub>O</sub> = 8 mA				V
V <sub>hys</sub>	Hysteresis voltage (V <sub>IT+</sub> – V <sub>IT-</sub> )				50		mV
Vo	Output voltage	$V_{ID} = 200 \text{ mV}, I_O = -8 \text{ mA}, \text{ See Figure 7}$		2.4			V
v <sub>O</sub>	Output voltage	$V_{ID} = -200 \text{ mV}, I_{O} = 8 \text{ mA}, Se$			0.4	V	
		$V_A$ or $V_B = 12 V$			0.20	0.35	
I <sub>A</sub> or	Puo input gurrent	$V_A$ or $V_B = 12 \text{ V}$ , $V_{CC} = 0 \text{ V}$	Other input		0.24	0.40	mA
I <sub>B</sub>	Bus input current	$V_A$ or $V_B = -7 V$	at 0 V	-0.35	-0.18		ША
		$V_A$ or $V_B = -7 V$ , $V_{CC} = 0 V$		-0.25	-0.13		
C <sub>ID</sub>	Differential input capacitance	$V_{ID} = 0.4 \sin (4E6\pi t) + 0.5 V,$	DE at 0 V		15		рF
I <sub>CC</sub>	Supply current	D at 0 V or V <sub>CC</sub> and No Load				2.1	mA

<sup>(1)</sup> All typical values are at 25C and with a 3.3-V supply.

### RECEIVER SWITCHING CHARACTERISTICS

over recommended operating conditions unless otherwise noted

	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
t <sub>PLH</sub>	Propagation delay time, low-to-high-level output	$V_{ID} = -1.5 \text{ V to } 1.5 \text{ V, } C_L = 15 \text{ pF,}$		26	45	20
t <sub>PHL</sub>	Propagation delay time, high-to-low-level output	See Figure 7		20	45	ns
t <sub>sk(p)</sub>	Pulse skew ( t <sub>PHL</sub> - t <sub>PLH</sub>  )				7	
t <sub>sk(pp)</sub>	Part-to-part skew <sup>(2)</sup>			5		
t <sub>r</sub>	Output signal rise time				5	
t <sub>f</sub>	Output signal fall time				6	

<sup>(1)</sup> All typical values are at 25C and with a 3.3-V supply

# DEVICE POWER DISSIPATION - PD

	PARAMETER	MIN	TYP MAX	UNIT	
$P_D$	Device power dissipation	$R_L=60$ , $C_L=50$ pF, Input to D a 50% duty cycle square wave at indicated signaling rate $T_A=85C$		197	mW

### **FUNCTION TABLES**

	DRIVER		RECEIVER				
INPUT	OUTPUTS		INPUT OUTPUTS		DIFFERENTIAL INPUTS	OUTPUTS	
D	Υ	Z	$V_{ID} = V_A - V_B$	R			
Н	Н	L	V <sub>ID</sub> ≤ -0.2 V	L			
L	L	Н	−0.2 V < V <sub>ID</sub> < 0.2 V	?			
Open	L	Н	0.2 V ≤ V <sub>ID</sub>	Н			

<sup>(2)</sup>  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.



### PARAMETER MEASUREMENT INFORMATION

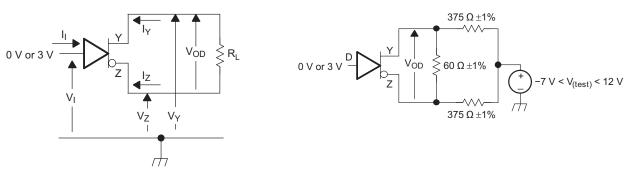


Figure 1. Driver V<sub>OD</sub> Test Circuit and Voltage and Current Definitions

Figure 2. Driver V<sub>OD</sub> With Common-Mode Loading Test Circuit

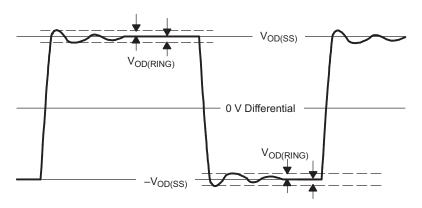


Figure 3.  $V_{\text{OD(RING)}}$  Waveform and Definitions

 $V_{OD(RING)}$  is measured at four points on the output waveform, corresponding to overshoot and undershoot from the  $V_{OD(H)}$  and  $V_{OD(L)}$  steady state values.

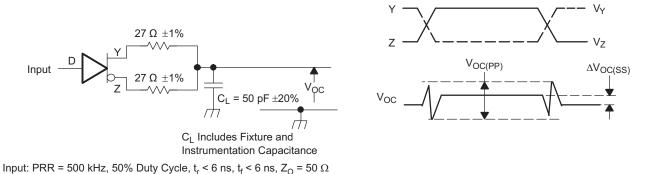
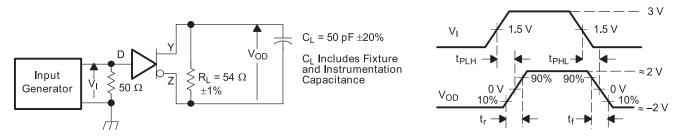


Figure 4. Test Circuit and Definitions for the Driver Common-Mode Output Voltage

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### PARAMETER MEASUREMENT INFORMATION (continued)



Generator: PRR = 500 kHz, 50% Duty Cycle,  $t_{\rm r}$  < 6 ns,  $t_{\rm f}$  < 6 ns,  $Z_{\rm O}$  = 50  $\Omega$ 

Figure 5. Driver Switching Test Circuit and Voltage Waveforms

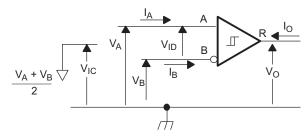


Figure 6. Receiver Voltage and Current Definitions

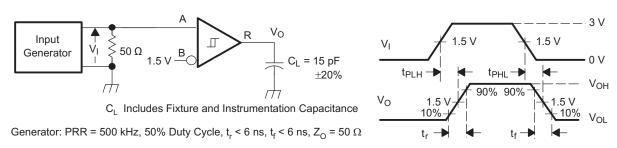


Figure 7. Receiver Switching Test Circuit and Voltage Waveforms

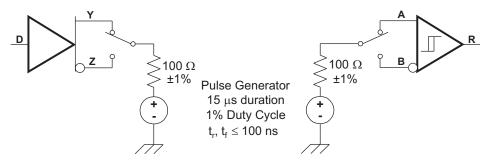
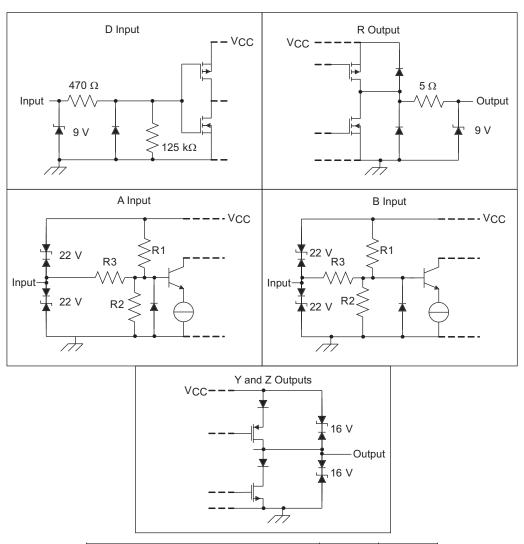


Figure 8. Test Circuit, Transient Over Voltage Test



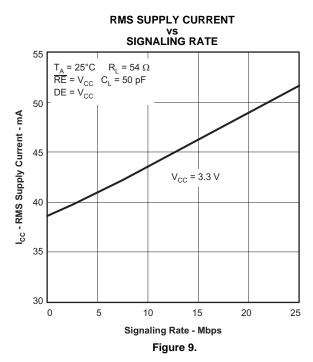
### **EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS**



	R1/R2	R3
SN65HVD379	9 kΩ	45 kΩ



### TYPICAL CHARACTERISTICS



# VS BUS INPUT VOLTAGE 250 $T_{\Delta} = 25^{\circ}C$ $\frac{\Lambda}{RE} = 0 \text{ V}$ 200 DE = 0 V 150 I<sub>1</sub> - Bus Input Current - µA 100 50 $V_{CC} = 3.3 \text{ V}$ 0 -50 -100 -150 -200 -4 5 14 V<sub>I</sub> - Bus Input Voltage - V Figure 10. **DRIVER HIGH-LEVEL OUTPUT CURRENT**

**BUS INPUT CURRENT** 

# **DRIVER LOW-LEVEL OUTPUT CURRENT** vs LOW-LEVEL OUTPUT VOLTAGE 0.14 V<sub>CC</sub> = 3.3 V DE = V<sub>CC</sub> 0.12 IoL - Driver Low-Level Output Current - A D = 0 V0.1 0.08 0.06 0.04 0.02 0 -0.020 1.5 2 V<sub>OL</sub> - Low-Level Output Voltage - V Figure 11.

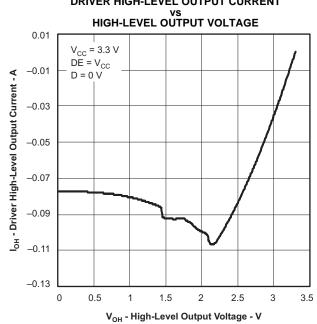
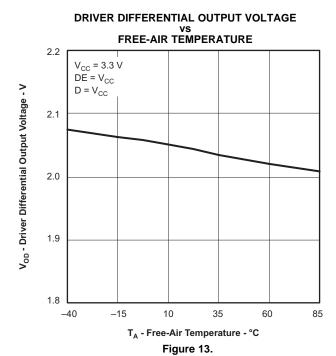
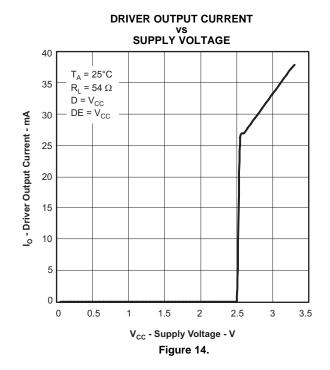


Figure 12.



# **TYPICAL CHARACTERISTICS (continued)**









7-Aug-2014

#### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN65HVD379D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP379	Samples
SN65HVD379DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP379	Samples
SN65HVD379DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP379	Samples
SN65HVD379DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP379	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.



# PACKAGE OPTION ADDENDUM

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# PACKAGE MATERIALS INFORMATION

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# TAPE AND REEL INFORMATION

### **REEL DIMENSIONS**



### **TAPE DIMENSIONS**



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### TAPE AND REEL INFORMATION

### \*All dimensions are nominal

Device	_	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65HVD379DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN65HVD379DR	SOIC	D	8	2500	367.0	367.0	35.0	

# D (R-PDSO-G8)

# PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



# D (R-PDSO-G8)

# PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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